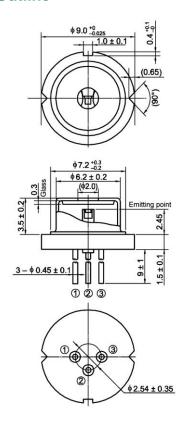


HL6319G/20G

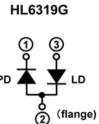
638nm/10mW

AlGaInP Laser Diode

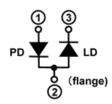
Outline



Internal Circuit



HL6320G



(unit: mm)

Features

- Optical output power: 10mW(CW)
- Visible light output:638nm Typ.
- Low operating current: 95mA Max.
- Low operating voltage: 2.7V Max.
- Single transverse mode
- TM mode oscillation

Application

- Laser lever
- Laser module
- Optical equipment for measurement

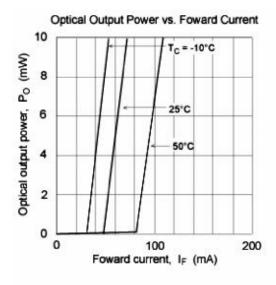
Absolute Maximum Ratings (Tc=25°C)

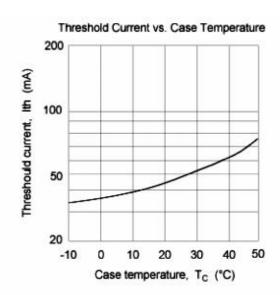
| Item | Symbol | Ratings | Unit |
|-----------------------|--------------------|-----------|------|
| Optical output power | Ро | 10 | mW |
| LD Reverse Voltage | V _{R(LD)} | 2 | V |
| PD Reverse Voltage | V _{R(PD)} | 30 | V |
| Operating Temperature | Topr | -10 ~ +50 | °C |
| Storage Temperature | Tstg | -40 ~ +85 | °C |

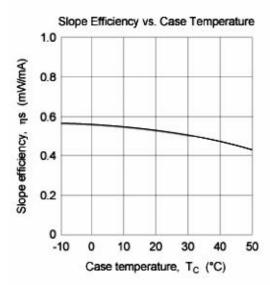
Optical and Electrical Characteristics (Tc=25°C)

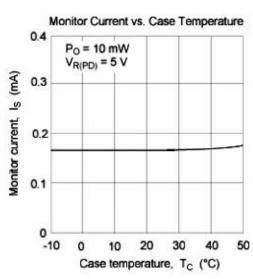
| Parameter | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|--------|------|------|------|-------|---------------------------------|
| Threshold current | Ith | 20 | 50 | 75 | mA | - |
| Operating current | lop | - | 70 | 95 | mA | Po=10mW |
| Operating voltage | Vop | - | - | 2.7 | V | Po=10mW |
| Slope efficiency | ηѕ | 0.3 | 0.5 | 0.7 | mW/mA | 6(mW)/(I (8mW) -I (2mW)) |
| Monitor current | Is | 0.05 | 0.17 | 0.30 | mA | Po=10mW, V _{R(PD)} =5V |
| Lasing Wavelength | λр | 625 | 638 | 640 | nm | Po=10mW |
| Beam divergence Parallel to the junction | θ// | 5 | 8 | 11 | 0 | Po=10mW FWHM |
| Beam divergence Perpendicular to the junction | θ⊥ | 25 | 31 | 37 | 0 | Po=10mW FWHM |
| Astigmatism | As | - | 5 | - | μm | Po=10mW, NA=0.55 |

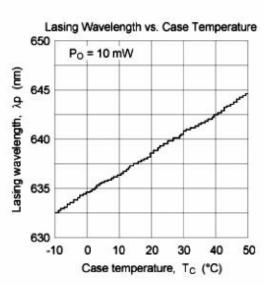
Typical Characteristic Curves

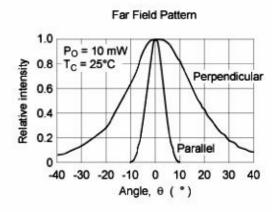












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